Doc No. TT4-EA-13620

Revision. 3

Schottky Barrier Diode

### DB2X41500L

Unit: mm

0.13

# **Panasonic**

## DB2X41500L

## Silicon epitaxial planar type

#### For frequency rectification

#### ■ Features

- · Low forward voltage VF
- Forward current (Average) IF(AV) = 3 A rectification is possible
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol: AD

#### ■ Packaging

Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

1. Cathoo 2. Anode				
Panasonic	Mini2-F4-B			
JEITA	SC-109D			
Code	SOD-123			

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1.6

#### ■ Absolute Maximum Ratings Ta = 25 °C

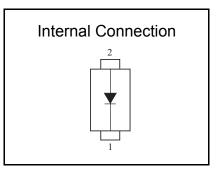
Parameter	Symbol	Rating	Unit
Reverse voltage	VR	40	V
Forward current (Average) *1	IF(AV)	3.0	Α
Non-repetitive peak forward surge current	IFSM	50 <sup>*2</sup>	Α
Non-repetitive peak forward surge current	IFSIVI	15 <sup>*3</sup>	Α
Junction temperature	Tj	125	°C
Operating ambient temperature	Topr	-40 to +85	°C
Storage temperature	Tstg	-55 to +125	°C

Note: \*1 TI = 60 °C / DC

\*2 Rectangle wave 1 cycle (Pulse width = 50 μs, non-repetitive peak current)

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\*3 50 Hz sine wave 1 cycle (Non-repetitive peak current)



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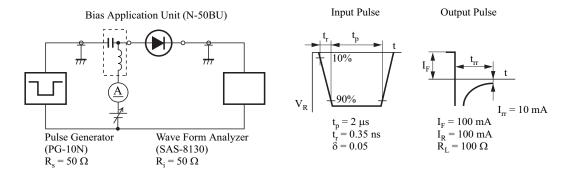
Schottky Barrier Diode

## DB2X41500L

#### ■ Electrical Characteristics Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	VF1	IF = 1.0 A		0.35	0.44	V
r orward voltage	VF2	IF = 3.0 A		0.47	0.55	
Reverse current	IR	VR = 40V		40	200	μΑ
Terminal capacitance	Ct	VR = 10 V, f = 1 MHz		70		pF
Doverse recovery time *1	trr	IF = IR = 100 mA		25		ns
Reverse recovery time *1		Irr = 10 mA, RL = 100 $\Omega$				

- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 Measuring methods for Diodes.
  - 2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.
  - 3. \*1 trr test circuit

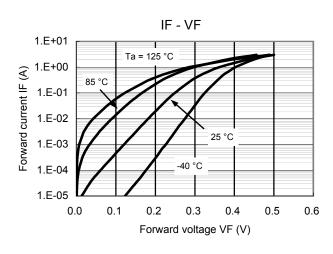


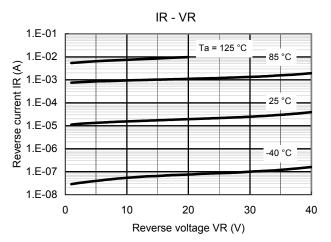
**Panasonic** 

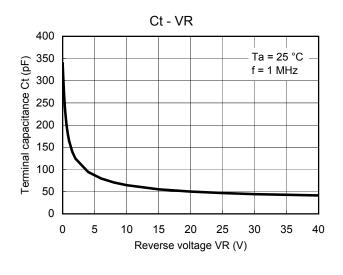
Schottky Barrier Diode

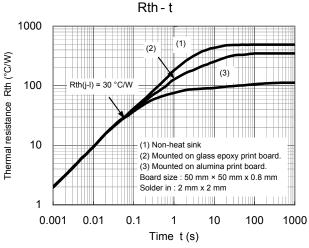
DB2X41500L

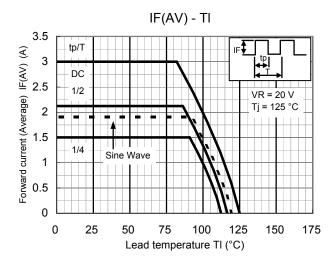
## Technical Data (reference)

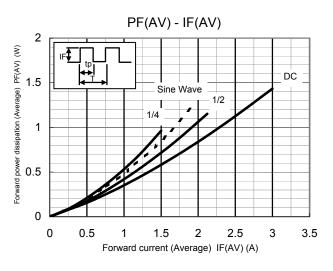












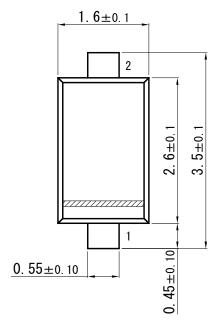
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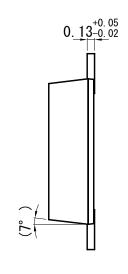
Schottky Barrier Diode

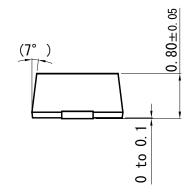
DB2X41500L

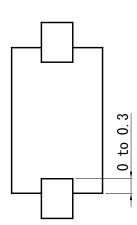
Mini2-F4-B

Unit: mm

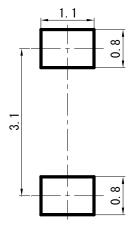








■ Land Pattern (Reference) (Unit: mm)



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